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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet	1	of	2
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Application Number

Filing Date

First Named Inventor

Art Unit

Examiner Name

Attorney Docket Number

Complete if Known

10/5/50

11/10/2006

Nicolas Boisbouvier et al.

2821

Tan Ho

PF020135

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

[illegible]

Examiner Signature	Tan Hoo	Date Considered	4/27/97
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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)		Complete If Known	
		Application Number	10/530,336
		Filing Date	11/10/2006
		First Named Inventor	Nicolas Boissbouvier et al.
		Art Unit	2821
		Examiner Name	Tan H
		Attorney Docket Number	PF020135

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
T.H.	AB	T.J. Ellis et al, INSTITUTE OF ELECTRICAL AND ELECTRONICS ENGINEERS: "MM-WAVE TAPERED SLOT ANTENNAS ON MICROMACHINED PHOTONIC BANDGAP DIELECTRICS", 1996 IEEE MTT-S International Microwave Symposium Digest, San Francisco, June 17-21, 1996, IEEE MTT-S Int'l Microwave Symposium Digest, New York, IEEE, US, vol. 2, 17 June 1996, pages 1157-1160	
T.H.	AC	J.D. ShumPERT et al. "PARALLEL-PLATE MODE REDUCTION IN CONDUCTOR-BACKED SLOTS USING ELECTROMAGNETIC BANDGAP SUBSTRATES" IEEE TRANSACTIONS ON MICROWAVE THEORY AND TECHNIQUES, IEEE INC., NEW YORK, US, vol. 47, no. 11, November 1999, pages 2099-2103	
T.H.	AD	W.Y. Leung et al. "SLOT ANTENNAS ON PHOTONIC BAND GAP CRYSTALS" IEEE TRANSACTIONS ON ANTENNAS AND PROPAGATION, IEEE INC., NEW YORK, US, vol. 45, no. 10, 1 October 1997, pages 1569-1570	
T.H.	AE	V. radiasic et al. "NOVEL 2-D PHOTONIC BANDGAP STRUCTURE FOR MICROSTRIP LINES" IEEE MICROWAVE AND GUIDED WAVE LETTERS, IEEE INC., NEW YORK, US, vol. 8, no. 2, 1 February 1998, pages 69-71	
T.H.	AF	Yun Tae-Yeoul et al. "One-Dimensional photonic bandgap resonator and varactor tuned resonators" MICROWAVE SYMPOSIUM DIGEST, 1999 IEEE MTT-S INT'L ANAHEIM, CA, US, 13-19 JUNE 1999, PISCATAWAY, NJ USA, IEEE, US 13 JUNE 1999, pages 1629 and 1632	
T.H.		COPY OF SEARCH REPORT DATED MAY 18, 2004	

Examiner Signature	Tan H	Date Considered	4/27/07
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